



Description

The TD101X series combine an AlGaAs infrared emitting diode as the emitter which is optically coupled to a silicon planar phototransistor detector in a plastic LSO package with the robust coplanar double mold structure. TD101X series provide the most stable isolation feature.

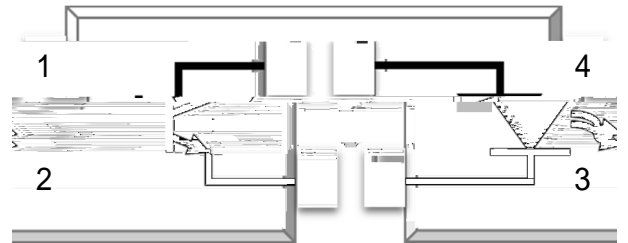
Features

- High isolation (000) * +S
- Temperature stability available see order information
- D, input with transistor output
- Operating temperature range . ((/ , to 110 / ,
- $I_{SO} \leq 1A$, , compliance
- +SL class 1
- Regulatory Approvals
 - 2L . 2L1(33)
 -)D1 . 14503!3.(. (6)D1077!. (8
 - , 9 , : G ; !< !=#1% G ; 77<7

Applications

- Switch mode power supplies
- Programmable controllers
- Household appliances
- Office equipment

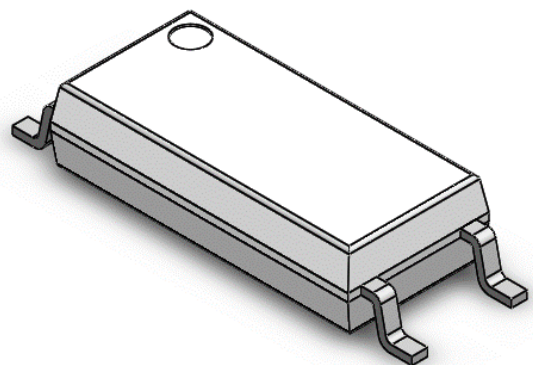
SCHEMATIC



PIN DEFINITION

1. Anode
2. Cathode
3. Emitter
4. Collector

PACKAGE OUTLINE





A ' SO# " TE MA (IM " M) ATIN ! S				
A * A + 1 T1 *	S@+ ; OL) AL21	24AT	4OT1
A4 2T				
Borward , urrent	AB	50	mA	
ea" Borward , urrent	AB	1	A	1
* e&erse) oltage) *	5)	
Anput ower Dissipation	A	100	m\$	
O2T 2T				
, ollector . 1mitter) oltage) , 10	70)	
1mitter . , ollector) oltage) 1 , 0	3)	
, ollector , urrent	A ,	(0	mA	
Output ower Dissipation	o	1(0	m\$	
, O+ +O4				
Total ower Dissipation	tot	?(0	m\$	
Asolation) oltage) iso	(000) rms	?
Operating Temperature	Topr	. ((C110	/ ,	
Storage Temperature	Tstg	. ((C1?(/ ,	
Soldering Temperature	Tsol	?50	/ ,	

Note 1. 100µs pulse, 100 ! "#e\$uenc%

Note 2. A& 'o# 1 ()nute, R. . * +0 , -0.



ELECTRICAL CHARACTERISTICS at Ta=25°C							
Symbol	Unit	Min	Typ	Max	Test Conditions	Notes	Ref
Forward Voltage	V _F	-	1.5	-	I _F = 10 mA, I _R = 0	A _B D (0 mA)	
Reverse Current	I _R	-	10	EA	V _R = 5 V	I _R (5 V)	
Input Capacitance	C _{in}	-	0	?	f = 1 MHz	I _D = 0 mA, I _F = 0	
Collector Current	I _C	-	100	nA	V _{CE} = 5 V, I _B = 0	I _C (5 V, 0 mA)	
Collector-Emitter Saturation Voltage	V _{CE(sat)}	0.7	-	-	I _C = 1 mA, I _B = 1 mA	A _B D (1 mA)	
Emitter-Emitter Saturation Voltage	V _{EE(sat)}	0.3	-	-	I _E = 1 mA, I _B = 1 mA	A ₁ D (1 mA)	
THERMAL CHARACTERISTICS							
Current Transfer Ratio	TD1010	-	0	500	G	A _B D (mA), I _D ()	
	TD101 ()	-	0	100			
	TD1015	-	100	0			
	TD1013	-	70	150			
	TD1017	-	10	250			
	TD101<	-	200	100			
	TD1011	-	50	0			
	TD101?	-	5	1?			
	TD101=	-	100	200			
	TD101!	-	150	=?			
	TD101?	-	??	.			
	TD101=	-	=!	.			
	TD101!	-	(5	.			
Collector-Emitter Saturation Voltage	V _{CE(sat)}	-	0.1	0.1	I _C = 10 mA, I _B = 1 mA	A _B D (10 mA), A ₁ D (1 mA)	
Isolation Resistance	R _{ISO}	10 ¹¹ ?	10 ¹¹ !	-	V = 50 V, I = 0	D, (00) % ! 0 C 50G * # ' #	
Bloating Capacitance	C _{AO}	-	0	1	f = 1 MHz	I _D = 0 mA, I _F = 0	
Turn-off Frequency	f _{off}	-	70	-	V _{CE} = 5 V, I _C = 1 mA, I _B = 1 mA	I _D = 0 mA, I _F = 0	=
Response Time (t _{rise})	t _r	-	17	Es	I _D = 0 mA, I _F = 1 mA	I _D = 0 mA, I _F = 1 mA	!
Response Time (t _{fall})	t _f	-	5	17	Es	I _D = 0 mA, I _F = 1 mA	!

Note 1. I_F = 10 mA

Note 2. I_B = 1 mA

CHARACTERISTICS - ES

Fig. 1 Forward Current vs. Ambient Temperature

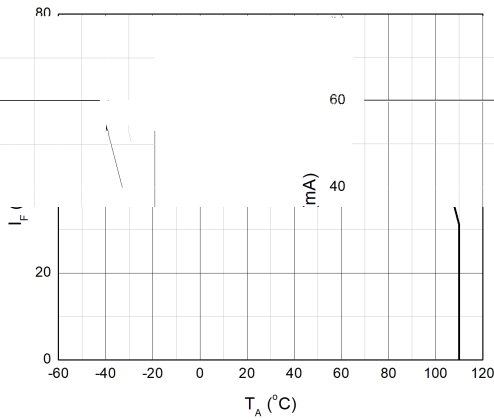


Fig. 2 Collector Power Dissipation vs. Ambient Temperature

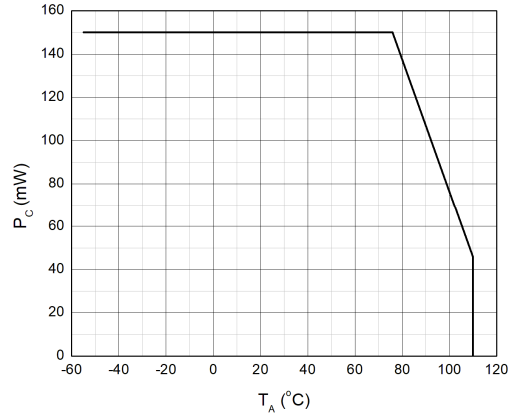


Fig. 3 Forward Current vs. Forward Voltage

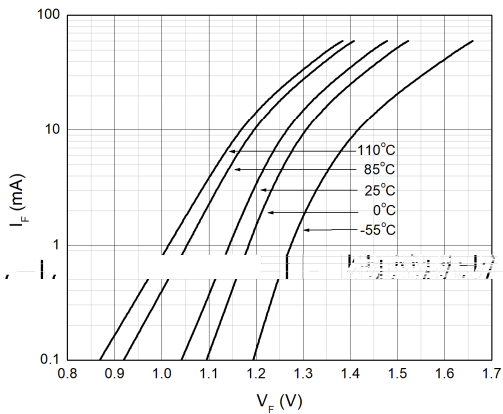


Fig. 4 Collector Dark Current vs. Ambient Temperature

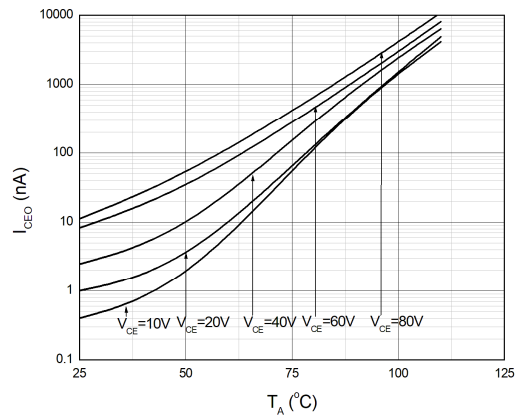


Fig. 5 Collector Current vs. Collector-Emitter Voltage

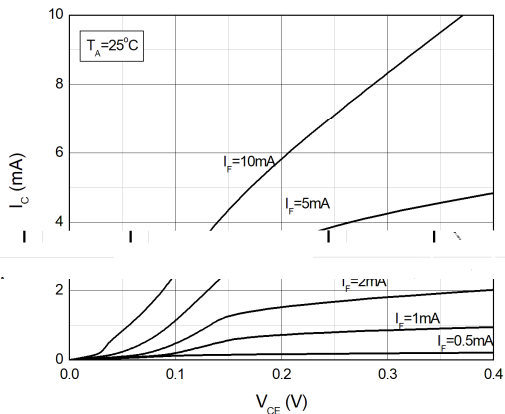
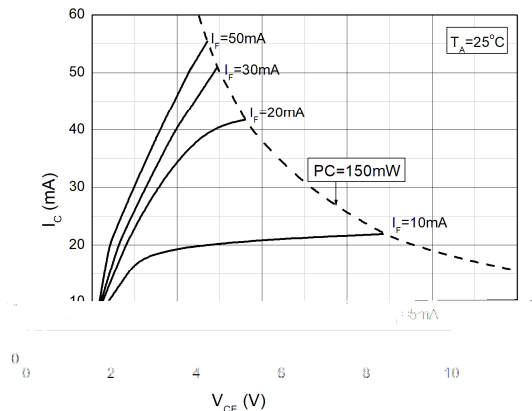


Fig. 6 Collector Current vs. Collector-Emitter Voltage



CHARACTERISTICS - ES

Fig. 5 Normalized Current Transfer Ratio vs. Collector Current

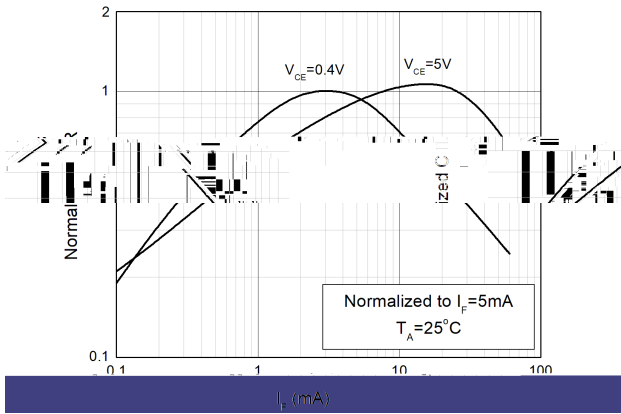


Fig. 8 Normalized Current Transfer Ratio vs. Ambient Temperature

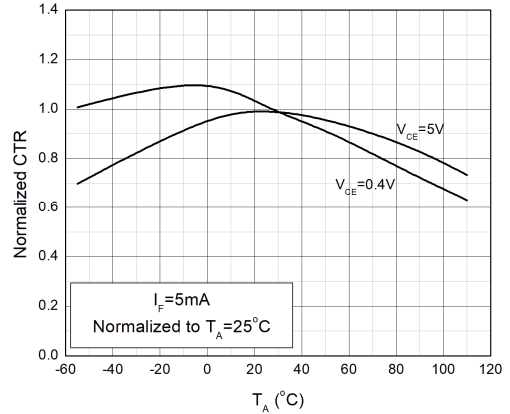


Fig. 9 Collector-Emitter Saturation Voltage vs. Ambient Temperature

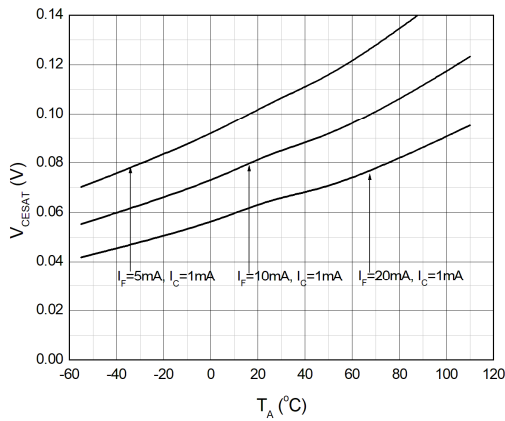


Fig. 10 Switching Time vs. Load Resistance

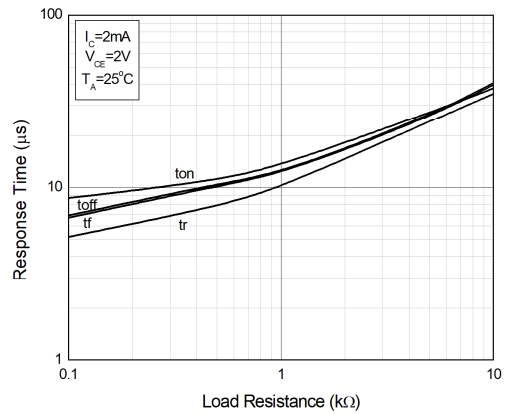
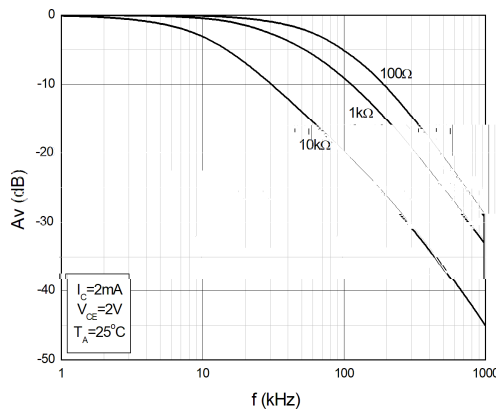


Fig. 11 Frequency Response



TEST CIRCUITS

Fig. 12 Test Circuit of Forward Time

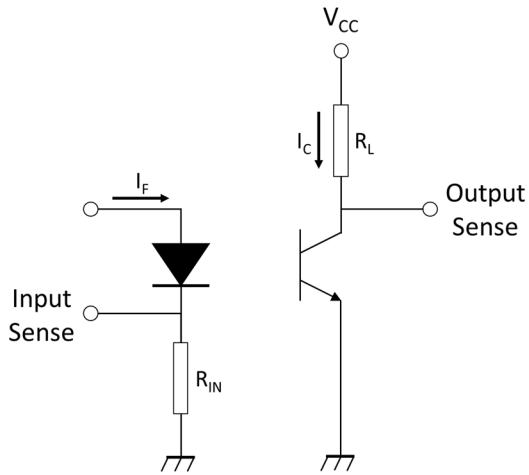


Fig. 13 Characteristic of Forward Time

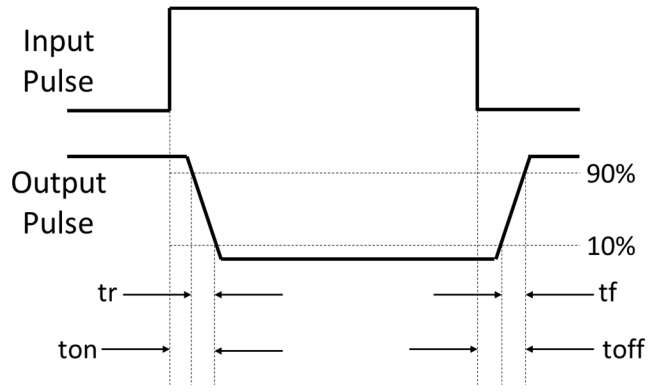
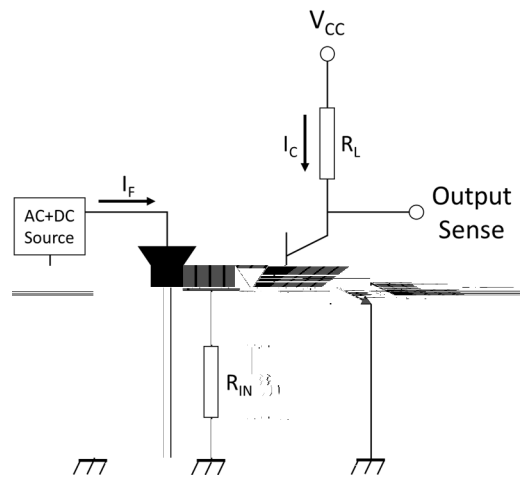
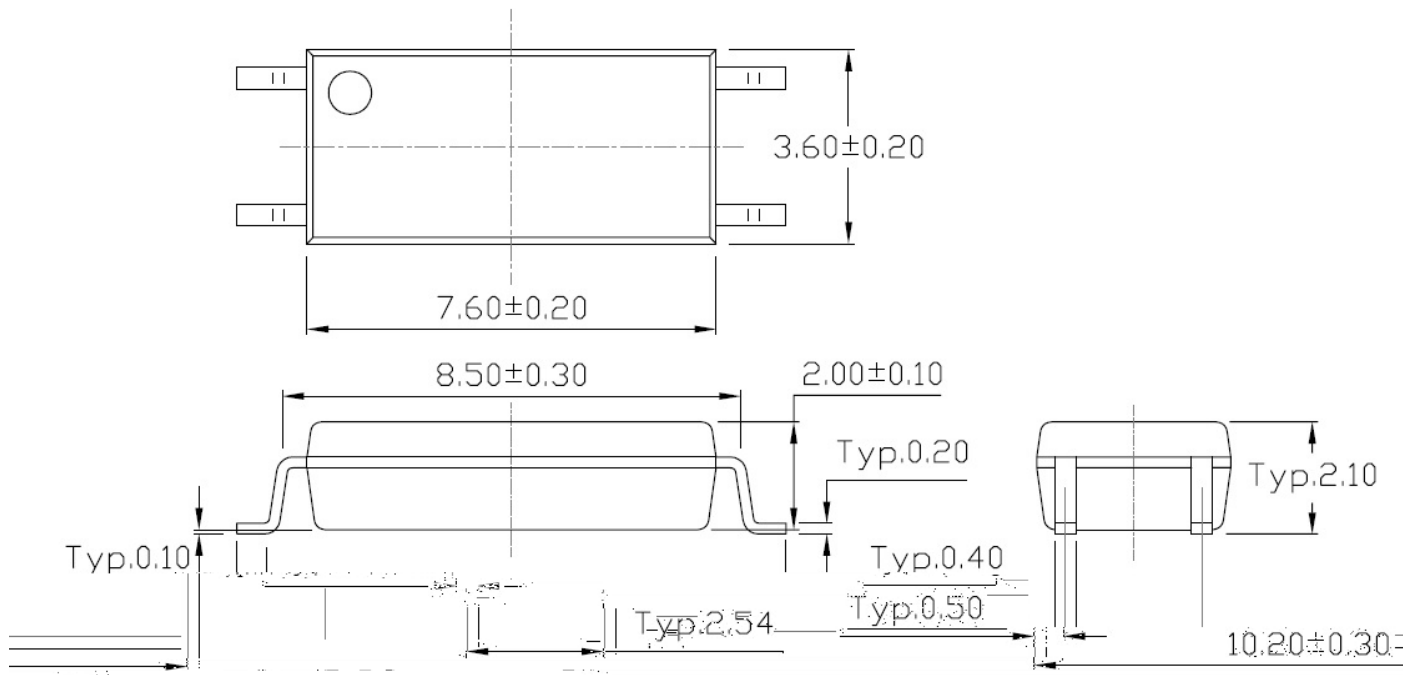


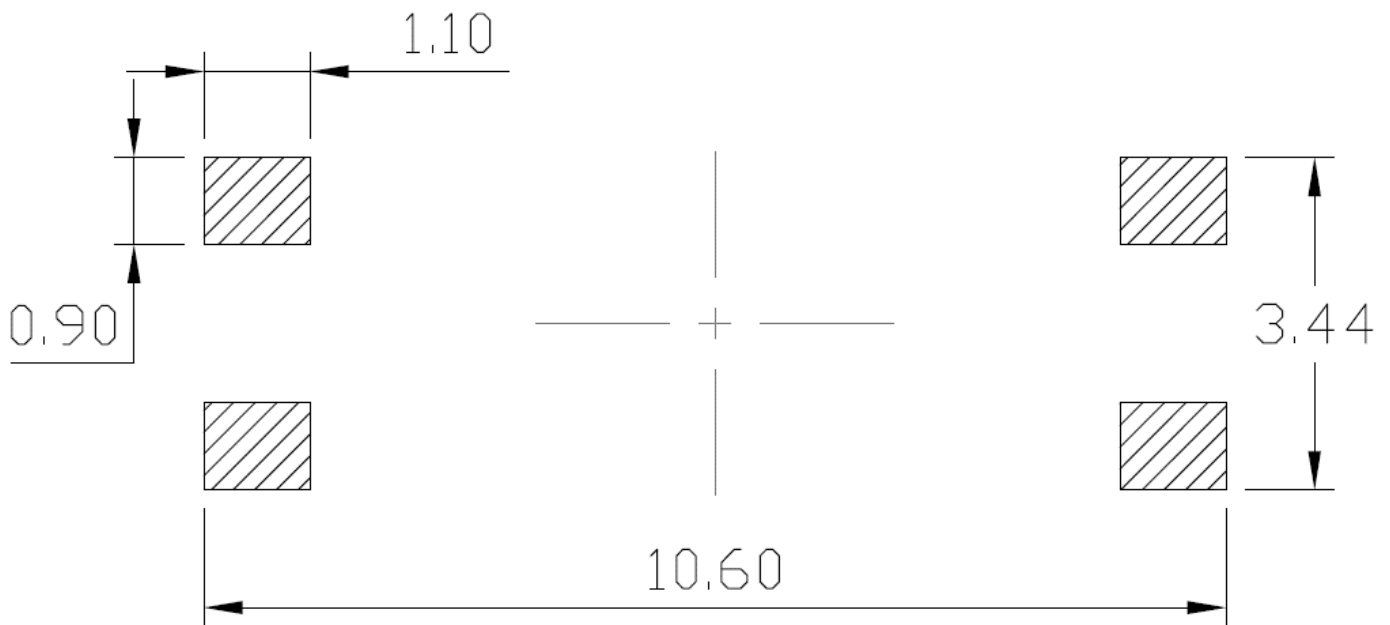
Fig. 14 Test Circuit of Reverse Time



PAC A ! E DIMENSIONS (Dimension\$ in mm & nle\$\$ other / i\$e \$tated=

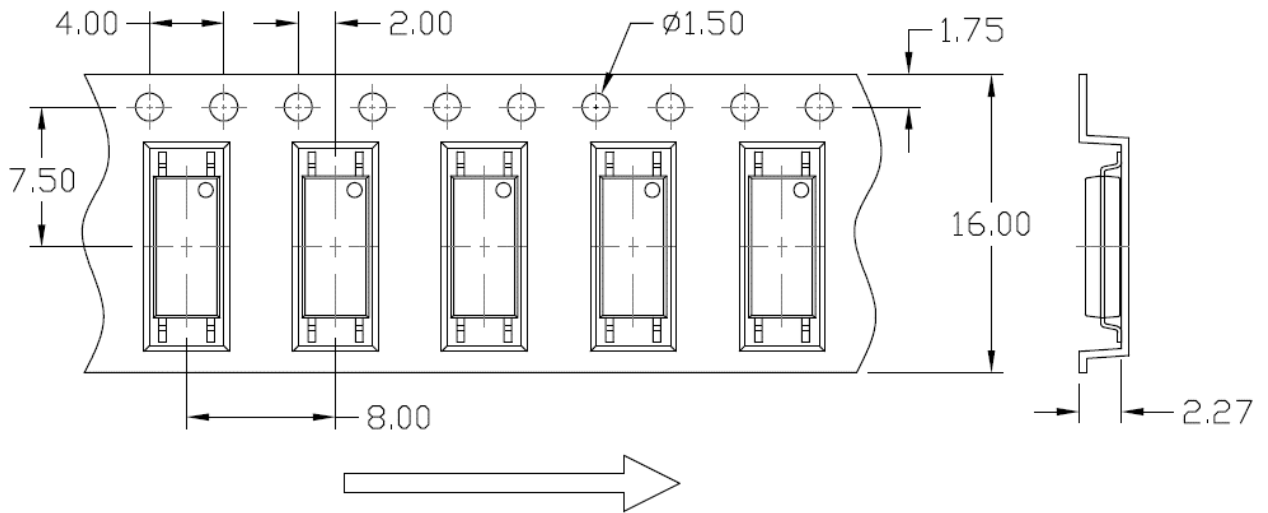


) ECOMMENDED SO#DE) MAS (Dimension\$ in mm & nle\$\$ other / i\$e \$tated=

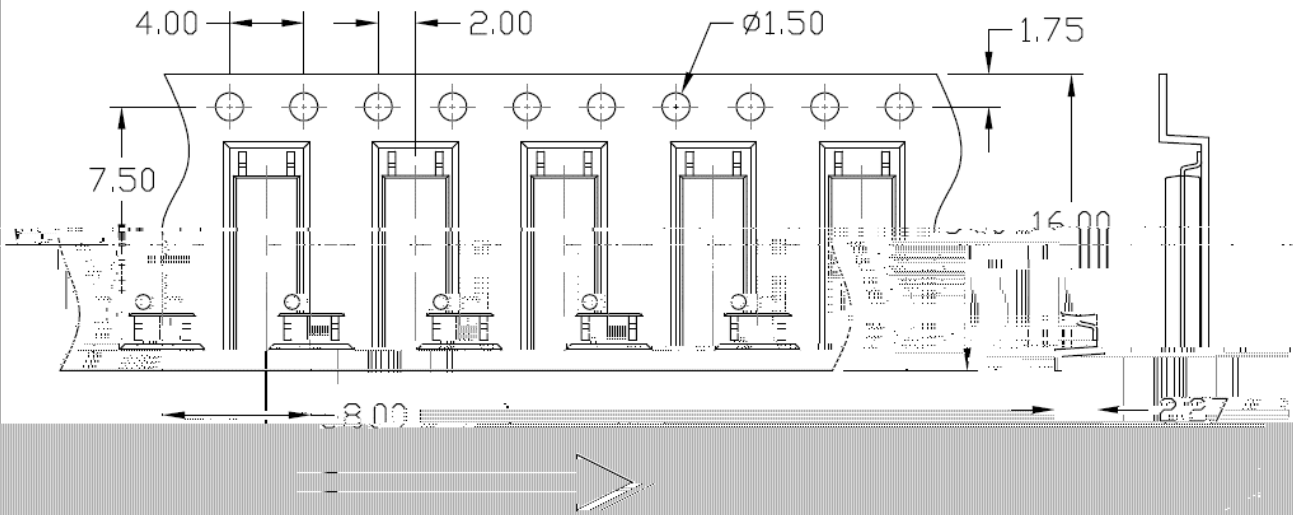


CA)) IE) TAPE SPECIFICATIONS (Dimension\$ in mm &nle\$\$ other / i\$e \$tated=

O%tion T1

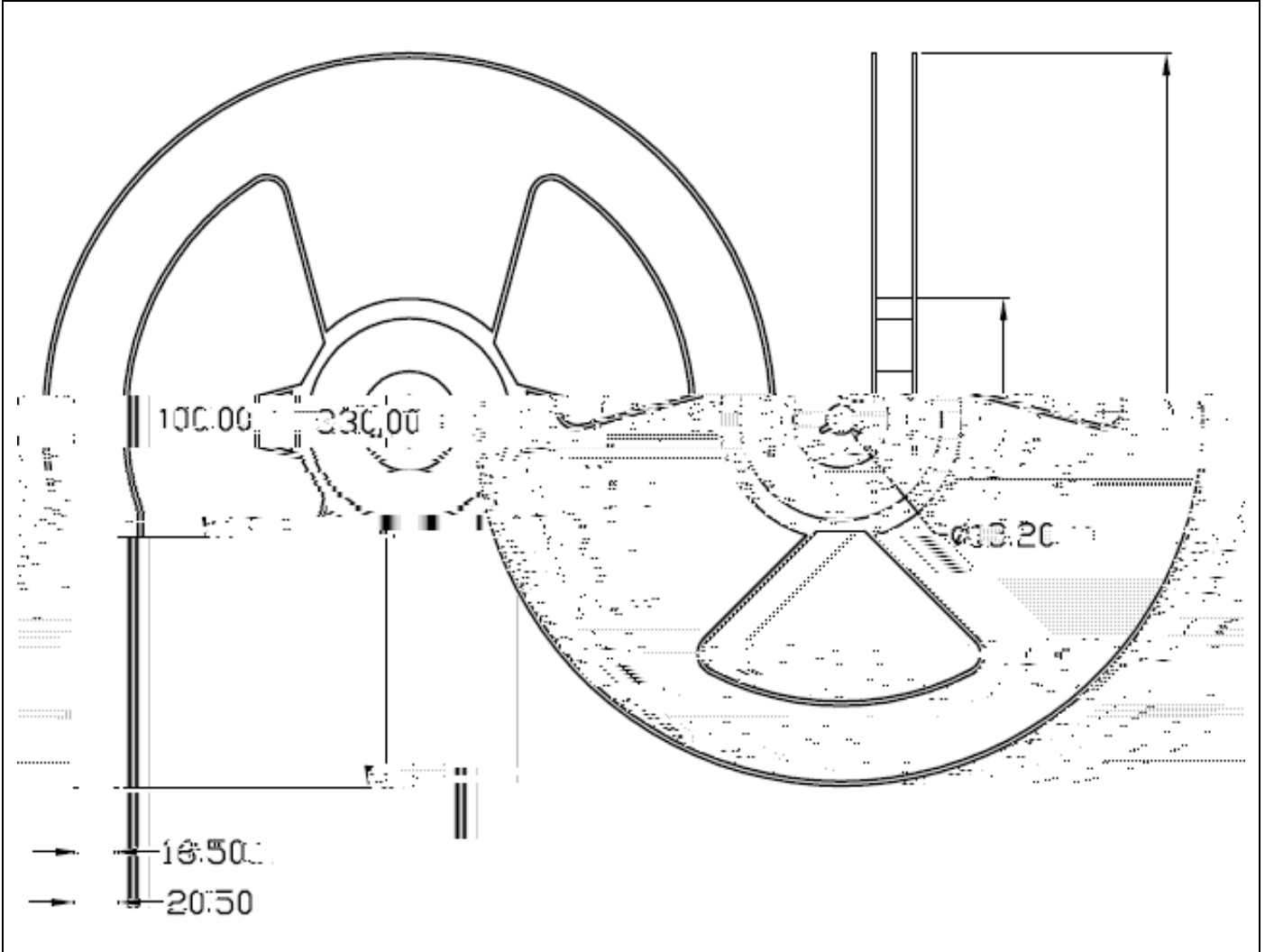


O%tion T2



EE# SPECIFICATIONS (Dimension\$ in mm & nle\$\$ other / i\$e \$tated=

O%tion T1 > T2





' O(SPECIFICATIONS () eel T<%e=

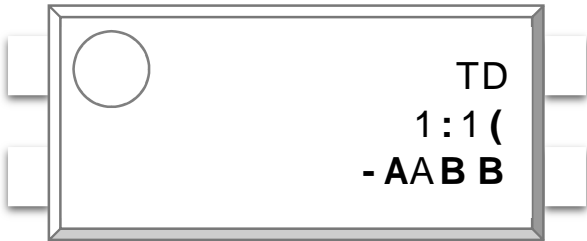
Inner ' o?

23 W 3 * /-cm 3 /-cm 3 -.9cm

O&ter ' o?


OPTIONAL AND MAIN INFORMATION

MAIN INFORMATION

	<p>TD @ Company Abbr.</p> <p>1:1(@ Part Number)an2</p> <p>- @ -DE Option</p> <p>A @ Fiscal Year</p> <p>A @ Manufacturing . Code</p> <p>BB @ B or 2 Bee2</p>
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OPTIONAL INFORMATION

FEATURE INFORMATION

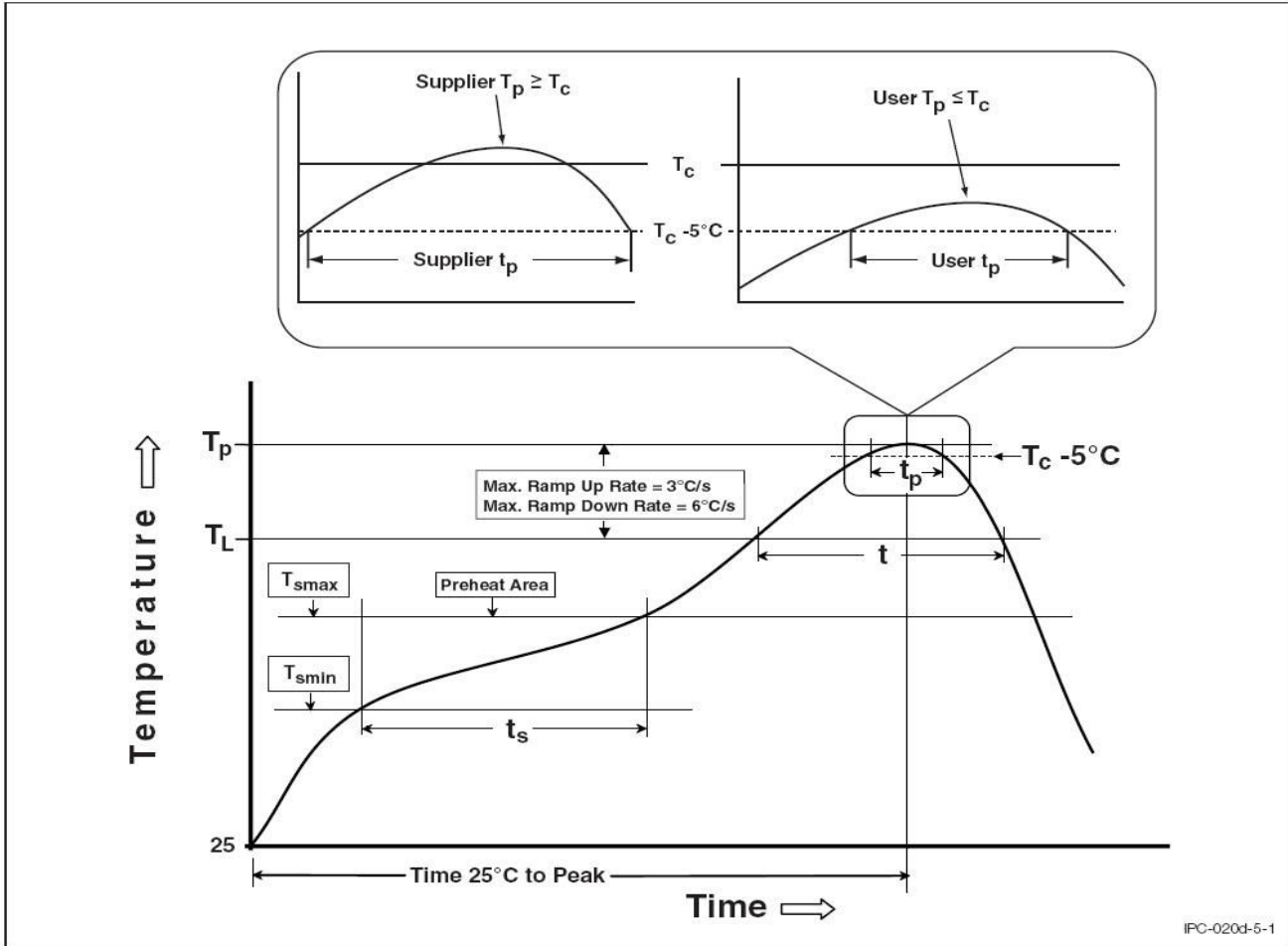
<p>TD1:1 (CD=3! -</p> <p>TD : , company Abbr#</p> <p>101X : *an" 60J1J?J=J!J(J5J3J7J<8</p> <p>K : Tape and *eel Option 6T1JT?8</p> <p>G : Green</p> <p>) :)D1 Option 6) or 4one8</p>	 <p>福建天电光电有限公司 FUJIAN LIGHTNING OPTOELECTRONIC CO., LTD.</p> <p>Part No : XXXXXXXXXXXXX Bin Code : X</p> <p>Lot No : XXXXXXXXXXXX</p> <p>Date Code : XXXX</p> <p>Q'ty : XXXX pcs</p>
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PACKING ANTIFES

Option	Antif	Antif Inner 1o?	Antif Outer 1o?
T1	=000 2nitsJ *eel	= *eelsJanner bo-	(Anner bo-JOuter bo- D ! (" 2nits
T?	=000 2nitsJ *eel	= *eelsJanner bo-	(Anner bo-JOuter bo- D ! (" 2nits

)EF#OB INFO)MATION

)EF#OB P)OFI#E



IPC-020d-5-1

Profile Feature	Sn3P1 Assembly Profile	P13Free Assembly Profile
Temperature +in# T_{smin}	100	100
Temperature +a-# T_{smax}	100	100
Time t_s from T_{smin} to T_{smax}	50.1±0 seconds	50.1±0 seconds
* amp.up * ate t_L to t_s	=/ , Jsecond ma-#	=/ , Jsecond ma-#
Liquidous Temperature T_L	170	170
Time t_L + aintained Abo&e T_L	50 : 10 seconds	50 : 10 seconds
ea" ;ody ac"age Temperature	170, 170, 170	170, 170, 170
Time t within (/ , of 50/ ,	±0 seconds	±0 seconds
* amp.down * ate T_p to T_L	5/ , Jsecond ma-	5/ , Jsecond ma-
Time (/ , to ea" Temperature	5 minutes ma-#	7 minutes ma-#



DISCLAIMER

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The characteristic curves shown in this datasheet are representing typical performance which are not guaranteed.

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This product is not intended to be used for military, aircraft, automotive, medical, life sustaining or lifesaving applications or any other application which can result in human injury or death.

Please contact TDLED sales agent for special application request.

Immersion unit's body in solder paste is not recommended.

Parameters provided in datasheets may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated in each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify TDLED's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Discoloration might be occurred on the package surface after soldering, reflow or long time use. It neither impacts the performance nor reliability.